## GLA University , Mathura

## B.Tech Ist Year Ist Semester

## First midterm Examination 2010-2011

Max. Time: 1.5 hrs. **Physics** M.M.:40 Note: Attempt all sections Section A Attempt all questions  $1 \times 10 = 10$ Q.1 Earth is (i) a non - inertial frame (iii) inertial frame at night and non-inertial at day (ii) an inertial frame (iv) None of these Q.2 The postulates of special theory of relativity are applicable to (i) Accelerated frame (ii) Inertial frame (iii) Stationary frame (iv) None of these Q.3. In Lorentz transformations (ii)  $x' = x - vt/\sqrt{1 - v^2/c^2}$  (iii)  $x' = x + vt/\sqrt{1 - v^2/c^2}$ (i)  $x' = x/\sqrt{1 - v^2/c^2}$ (iv)  $x' = x \cdot vt / \sqrt{1 - v^2/c^2}$ Q.4 Two photons approach each other. Their relative velocity will be (i) 2c (ii) c (iii) c/2 (iv) 0 Q.5 Decay of µ-mesons supports (i) Time dilation (ii) Length contraction (iii) relativity of mass (iv) Relativity of energy Q.6 Effective mass of e depends on (a) Electron concentration of conduction band (b) Hole concentration of valance band (c) Curvature of conduction band (d) Width of valance band Q.7 The forbidden energy gap of carbon in diamond structure is (a) 0.7 ev (b) 1 ev (c) 0.01ev (d) None of these

Q.8 The Fermi level in an n-type semiconductor at OK lies

(a) Below the donor level

(b) Half way betwee	n the conduction band and donor level	•
(c) Coincides with in		
(d) None of these		
Q.9 The density of ca	arriers in a pure semiconductor is proportion	ional to
(a) Exp (-Eg/K <sub>B</sub> T)	(b) Exp (-2Eg/K <sub>B</sub> T)	
(c) Exp (-Eg/K <sub>B</sub> T <sup>2</sup> )	(d) Exp (-Eg/2K <sub>B</sub> T)	
Q.10 The depletion r	egion in an open circuited p-n junction con	ntains
(a) Electrons	(b) Holes	
(c) Uncovered immol	pile impurity ions	
(d) Neutralized impur	ity atoms	
	Section-B	
Attempt any two que	· .	8x2 = 16
Q.2 (a) Prove the relat	relativistic the form of Newton's second low $\vec{F} = m d\vec{v} / dt (1 - v^2/c^2)^{-3/2}$ tion $E^2 - p^2 c^2 = m_o^2 c^4$ where p is the momentument that no particle can attain a velocity	um. 4
	r and acceptor impurities. Give an example	
	on of donor and acceptor level in an intrin	<b>_</b>
		2
·	Section C	
Attempt any one ques	tion	
<b>Q.1</b> Deduce Einstein's i	mass-energy relation E=mc <sup>2</sup> and discuss it.	. Give some evidence showing its validity. $14x1 = 14$
<b>2.2(a)</b> Distinguish between tration for an in	ween intrinsic and extrinsic semiconduct trinsic semiconductor.	tor obtain an expression for the carrier
(b) What is Hall effect	. Obtain an repression for Hall coefficient.	7